

# Comparison of $O_2$ - $N_2$ and $H_2$ Plasma Cleaning for EUV Applications

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# Outline

- Fundamentals of plasma cleaning
  - ...with air
  - ...with hydrogen
- Measurement of hydrocarbon removal
- Understanding Cleaning Rate
  - Simple model (flow, pressure, distance)
- Comparison of  $\text{N}_2\text{-O}_2$  vs.  $\text{H}_2$
- System design
- Conclusions



# Plasma cleaning with N<sub>2</sub>-O<sub>2</sub>

## Applications

- Vacuum systems/components with hydrocarbon contamination
- Cleaning of new chambers or after maintenance
- Prior to deposition of interface-sensitive films

## Advantages

- Removes hydrocarbons by chemical reaction with reactive oxygen species resulting in volatile products
- Feedstock gas free (air) or inexpensive (CDA)

## Disadvantages

- Not compatible with systems containing Ag or Ru
- May oxidize some surfaces if at elevated temperature
- Less efficient at removing double-bonded carbon compounds



# Plasma cleaning with Hydrogen

## Applications

- Cleaning materials that are incompatible with oxygen-based cleaning
- Reduction of metal oxide films

## Advantages

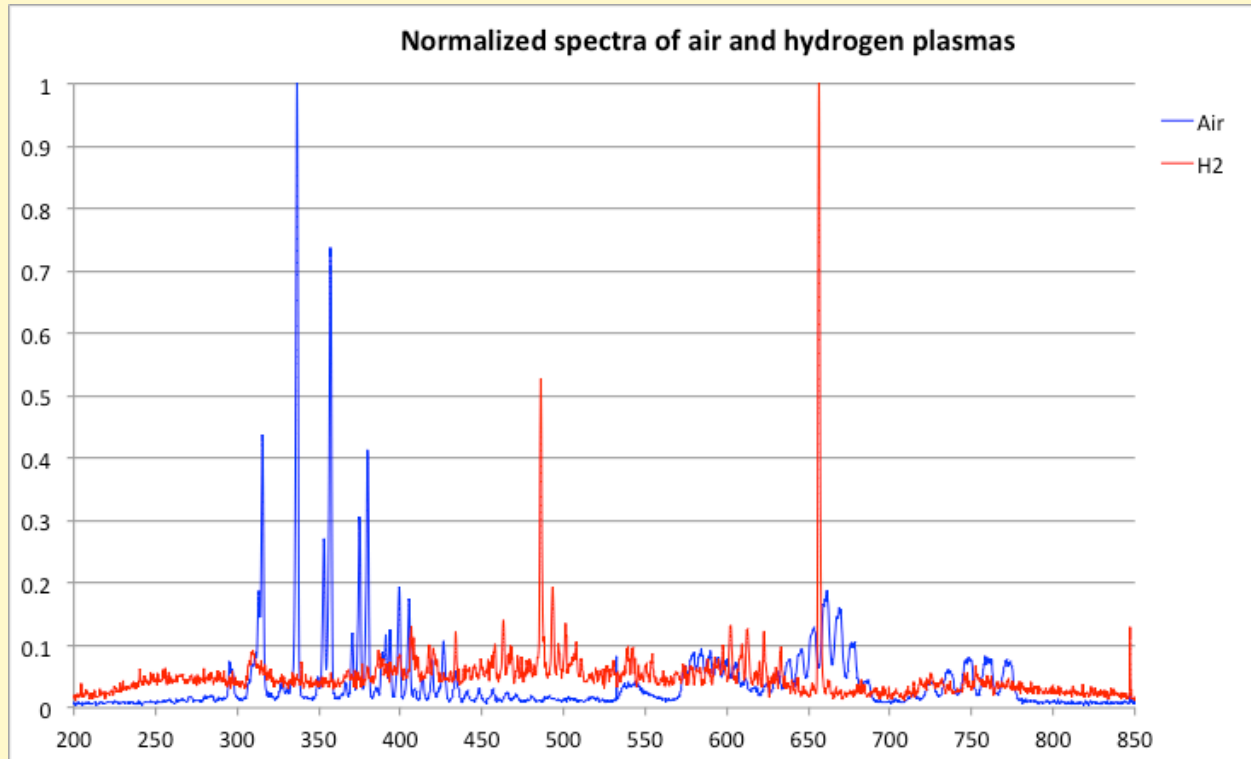
- As with air, innocuous by-products
- Increased gas mean-free-path (2x nitrogen)

## Disadvantages

- Gas manifold more complex (need to vent and purge)
- Material requirements along gas path
- Safety infrastructure/risks (point-of-use generator)



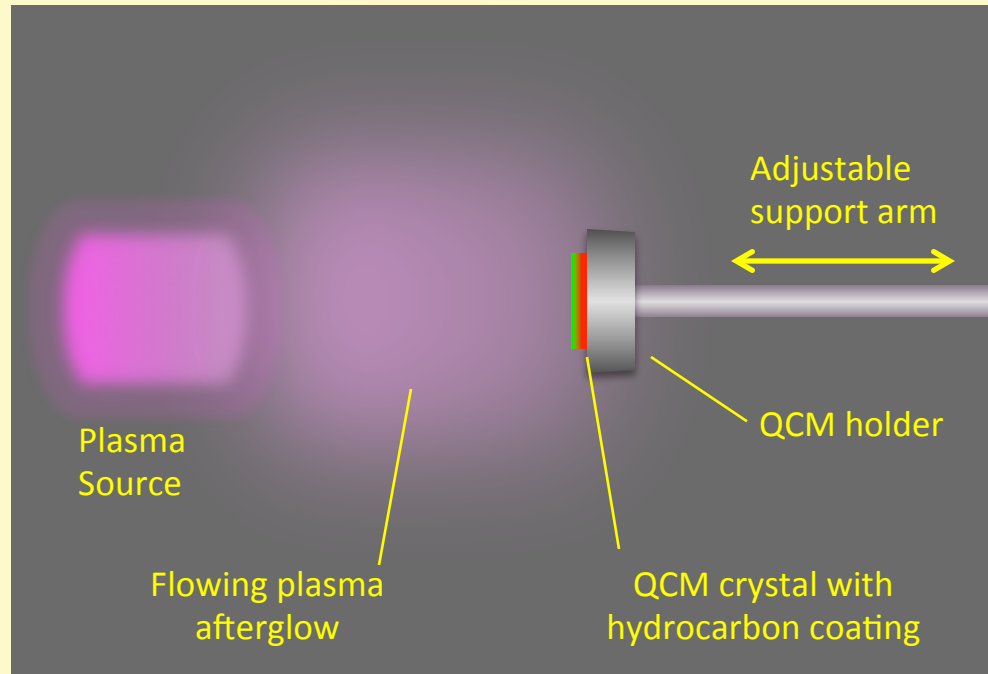
# Hydrogen and Air spectra



- Relative plasma strength tracks intensity of optical emission from plasma
- Optical emission from H2 in visible band is weak, plasmas appear to eye as dim



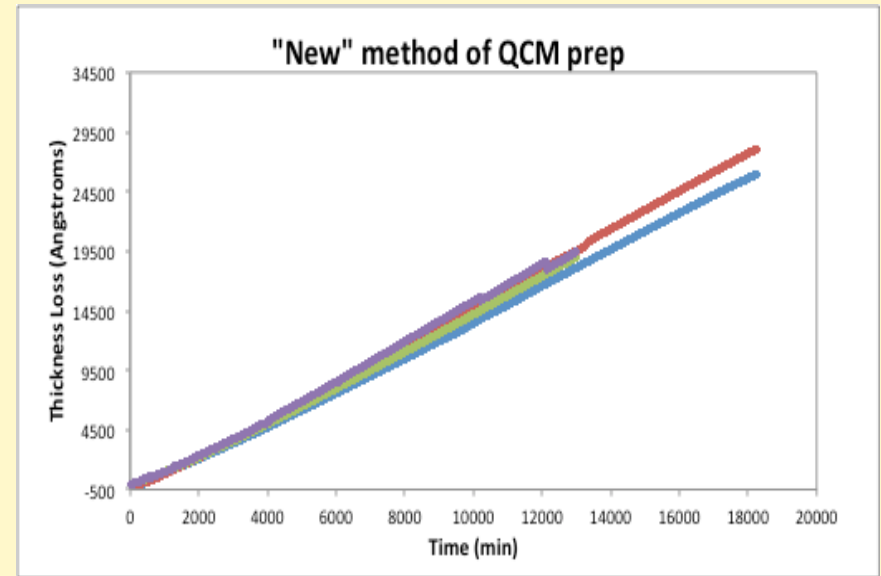
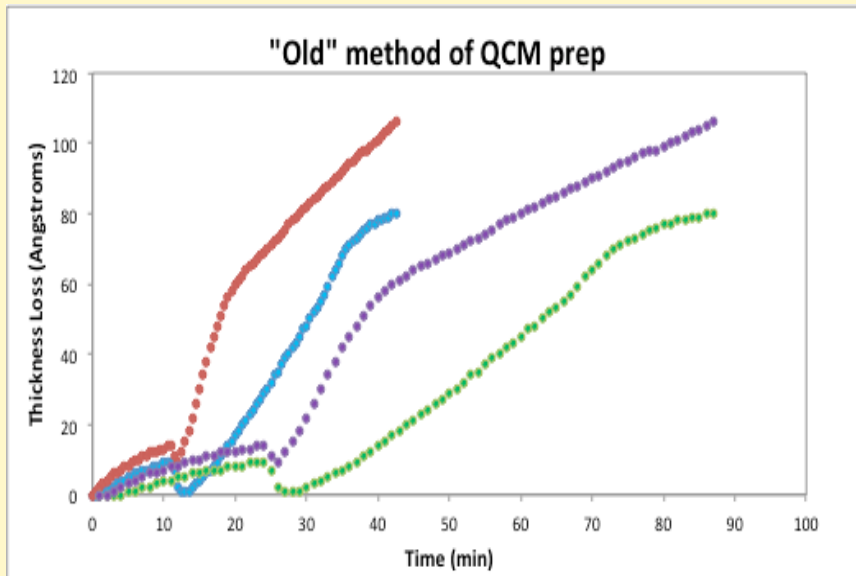
# Quantifying Hydrocarbon Cleaning



- Use established quartz crystal microbalance (QCM) tools
- Deposit hydrocarbon-based (HC) solid film on QCMs
- Remove HC layer using Evactron™ plasma cleaner
- Record  $\Delta(\text{thickness})$  versus time to calculate cleaning rate



# Hydrocarbon (HC) layer: preparation method matters



*Slope of line is proportional to cleaning rate*

Old method (FGM):

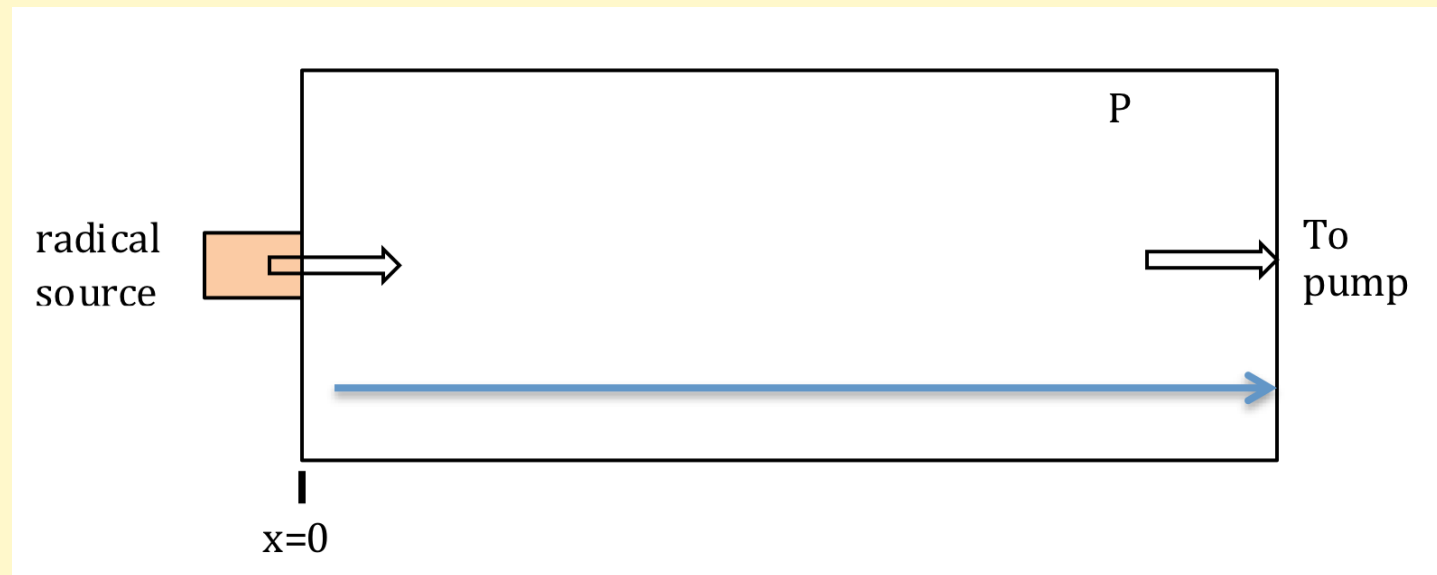
- Layers limited to 100-500 Å
- Slope (cleaning rate) not linear with time (variations in the properties of HC layers)
- Cleaning rates varied under "identical" preparation conditions

New method (CMR):

- High linearity over entire thickness
- Increase in film thickness (several microns)
- Results repeatable and consistent
- Parametric studies w/o breaking vacuum



# Pressure Effects: A Simple Model



#radicals at distance  $x = F * (\text{source flux}) * \exp(-x/R)$

where "F" is flow factor  $\approx f / (f + \text{constant})$

"R" is the loss-based "reaching distance"

But  $R \approx (\text{gas constant } k)/P$

and  $\text{source flux} \approx (\text{constant } \gamma) * P$



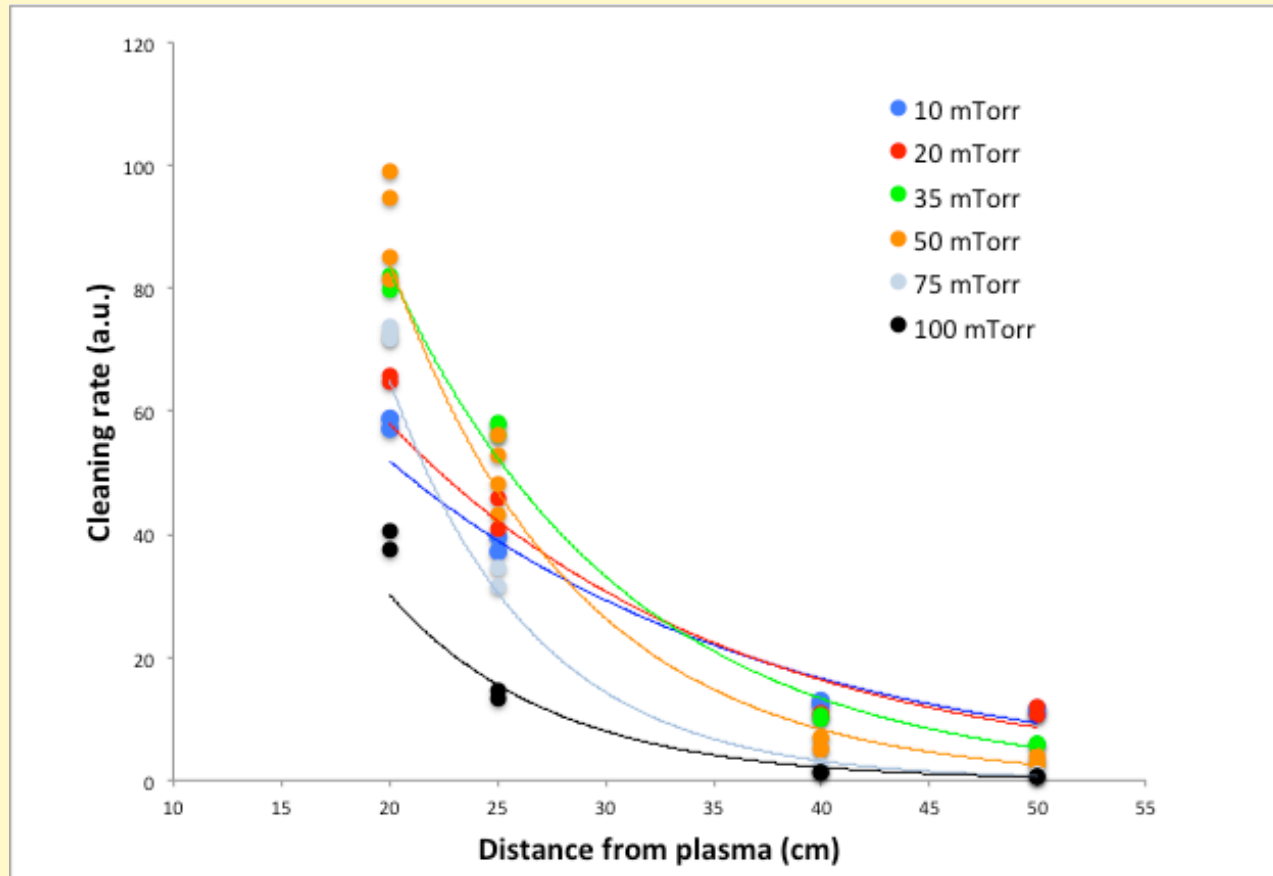


# Simple model (continued)

- Combining: normalized #radicals =  $F * P * \exp(-x * P/k)$
  - Pressure too low → reduced production of cleaning species
  - Pressure too high → reduced reach due to losses/scattering
- ★- 1) at a given distance from plasma there is an optimal pressure for maximum cleaning rate  
2) larger distances require lower pressures

*(Note: Effect of gas flow rate assumed constant for a given chamber and pump stack)*

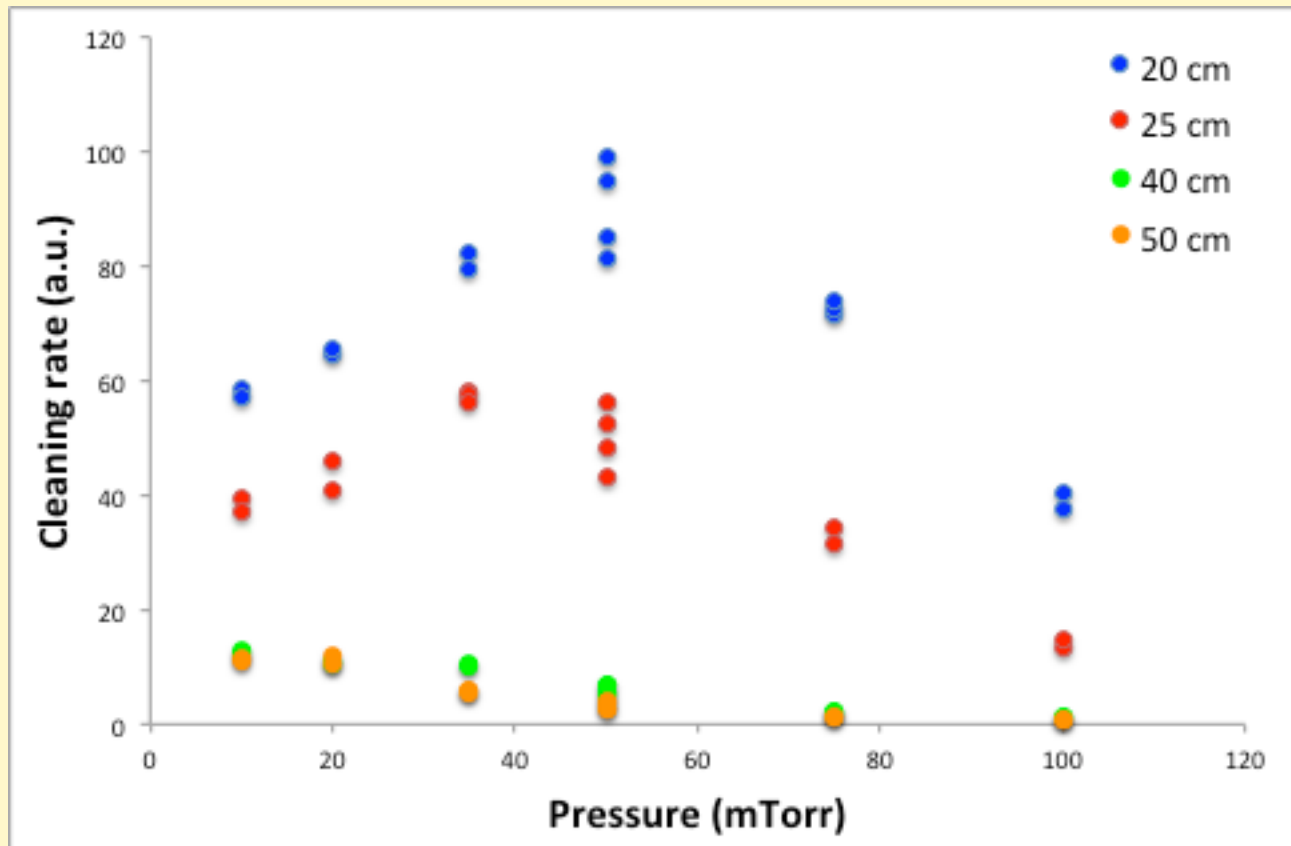
# Removal rates (air) vs. distance @ 20W



- Cleaning rate falls off exponentially away from source all pressures
- Highest rate occurs not at highest or lowest pressure



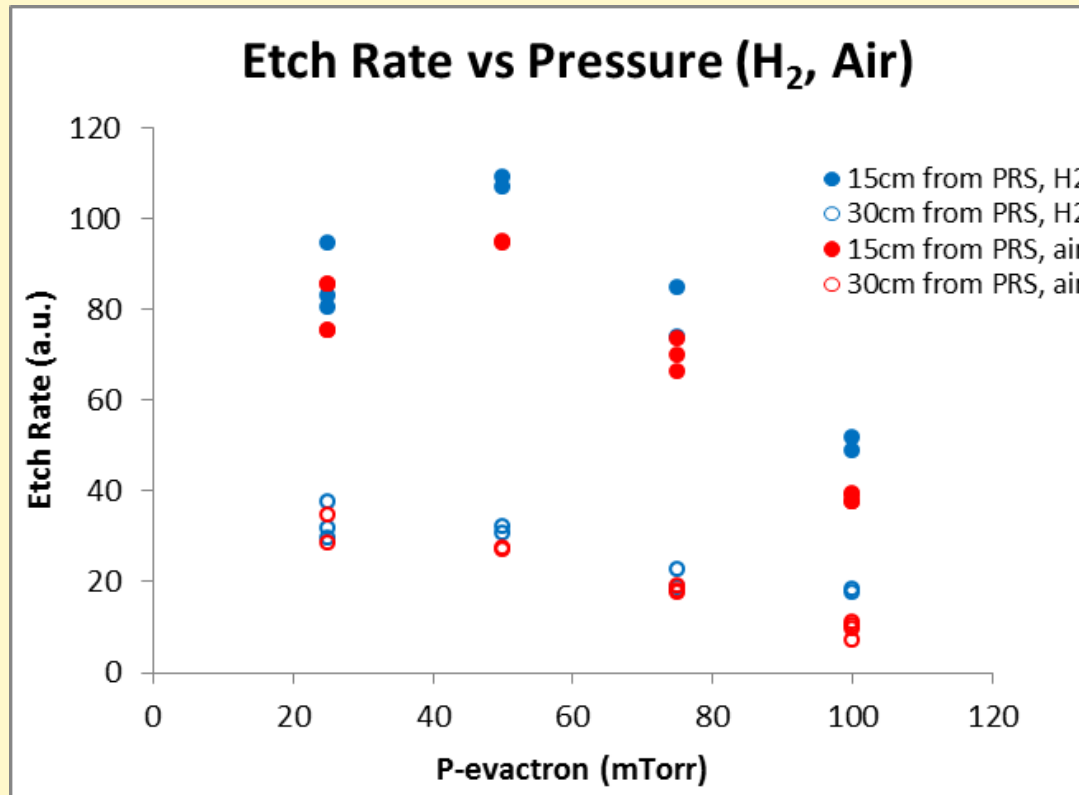
# Removal rates (air) vs. pressure @ 20W



- Optimal pressure depends on distance from plasma source



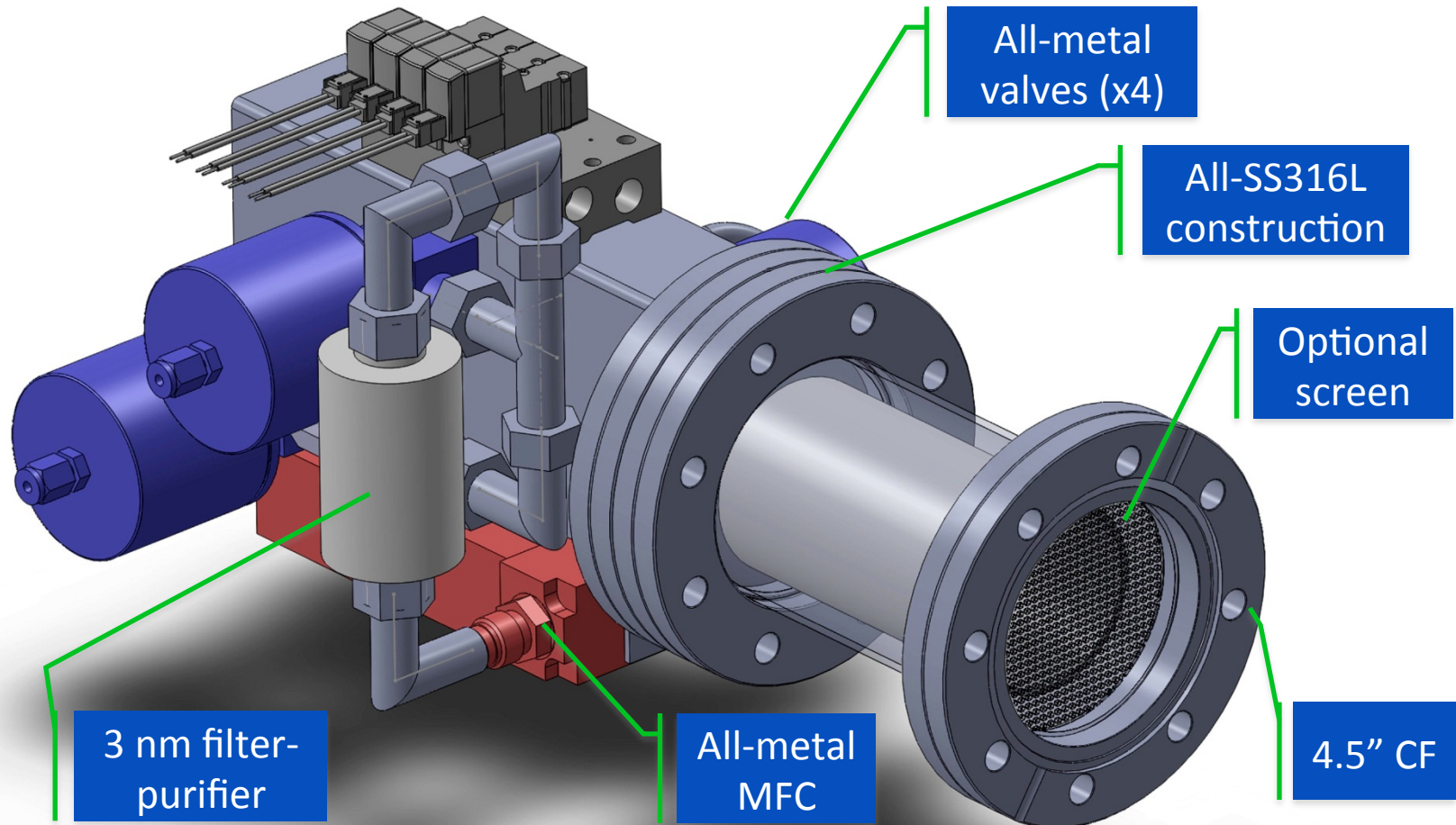
# Removal Rates in Air versus Hydrogen



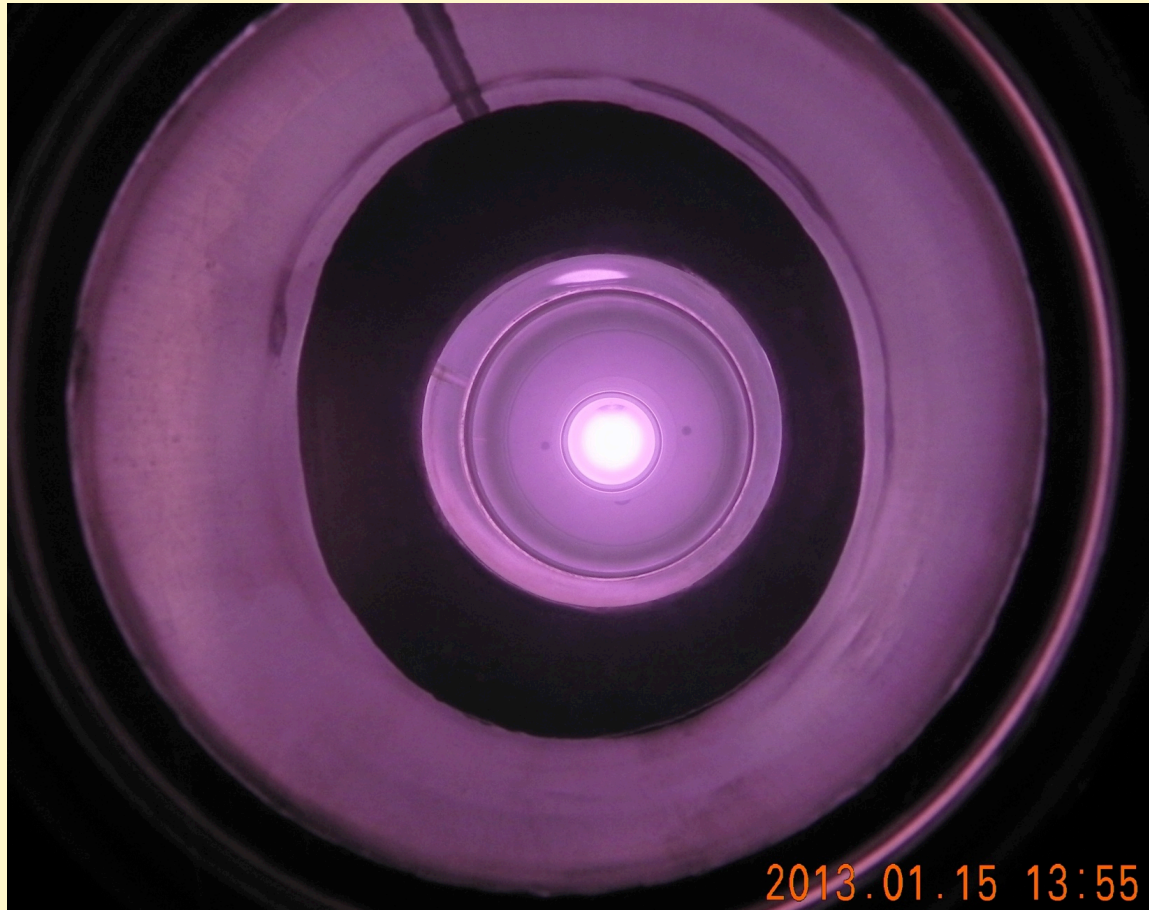
At 20 W plasma power, Hydrogen plasma removes hydrocarbons (HC) slightly faster than oxygen plasma under the same conditions



# Prototype $H_2$ Plasma Cleaning System



# 50 W plasma operating in H<sub>2</sub>



-New electrode design as seen through 6" CF cross



# Conclusions

- New electrode design capable of 50 W plasma power (> 150 W in limited tests)
- For both air ( $O_2$ - $N_2$ ) and hydrogen ( $H_2$ ) it was found that gas pressure selection is a key for maximizing cleaning rates
- Higher pressures increase scattering by the gas
- Lower pressures required to reach farther
  - Reduced pressure small effect on reactant concentration (since  $N_{\text{gas}} \gg n_{\text{electron}}$ )
- A stable method for hydrocarbon film preparation allows for parametric studies of plasma cleaning



# Prototype Technical Specs

- SS316L construction: no elastomers
- H<sub>2</sub> wets only metallic surfaces
- No/minimal ceramic materials
- Charge trapping screen option
- Low-particle and ultra-clean construction (SS 316L)
- Elastomer-free gas manifold: all-metal seal valves
- In-line 3 nm filter/purifier
- Clean room assembly and packaging

